

## Niobium – Silicon – Uranium

*Peter Rogl, Henri Noél*

### Introduction

Missing knowledge on the interaction of uranium silicide fuel and niobium from the burn-up triggered investigation of the Nb-Si-U ternary system.

Information on the constitution of the Nb-Si-U system was provided by two cooperating research groups [1993LeB, 2000Leb] reporting phase relations for the isothermal sections at 1000°C and 850°C, which are characterized by the existence of two ternary compounds: (1)  $U_2Nb_3Si_4$  ( $Sc_2Re_3Si_4$  type) and (2) closely related  $U_{2-x}Nb_{3+x}Si_4$ ,  $x \approx 0.25$ , with partially ordered  $Sm_5Ge_4$  type ( $Ce_2Sc_3Si_4$  type). Magnetic susceptibility and magnetization data were reported for weakly ferromagnetic  $U_2Nb_3Si_4$  [1993LeB, 2000Leb]. The various experimental activities related to the constitution of the ternary Nb-Si-U system are summarized in Table 1.

### Binary Systems

The binary boundary system Nb-U is from [Mas2]. The Nb-Si phase diagram was accepted in the version of [1995Sch], which was used in [2002Fer] as a base for thermodynamic assessment. The  $\alpha$ - $\beta$  polymorphic transformation of  $Nb_5Si_3$  takes place in the temperature range 1645 to 1935°C.  $Nb_3Si$  was proposed to exist in the temperature range from 1765 to 1975°C. The system Si-U is taken from reinvestigations by [1992Rem, 1993LeB, 1998Noe], but the uranium rich part of the diagram up to 4 at.% Si is from [1965Str]. Crystallographic and melting data pertinent to the Nb-Si-U system are listed in Table 2.

### Solid Phases

The crystal structures of the two ternary compounds were established from X-ray Rietveld refinements. Fully ordered and stoichiometric  $U_2Nb_3Si_4$  is isotypic with the  $Sc_2Re_3Si_4$  type (ordered ternary version of the  $Zr_5Si_4$  type) additionally confirmed from neutron powder data recorded at 1.4 K [1993LeB, 2000Leb]. Single phase  $U_2Nb_3Si_4$  was obtained from melted alloys annealed at 1350 to 1400°C. The second ternary phase was obtained at an off-stoichiometric formula  $U_{19.3}Nb_{37.4}Si_{43.3}$  (*i.e.*  $U_{2-x}Nb_{3+x}Si_4$ ,  $x \approx 0.25$ , from EMPA and Rietveld data) with the partially ordered  $Sm_5Ge_4$  type ( $Ce_2Sc_3Si_4$  type) [2000Leb]. Retarded reaction kinetics prevented the formation of a single-phase product for  $U_{2-x}Nb_{3+x}Si_4$  even after long term annealing treatments (up to 3000 h) still revealing significant amounts of  $U_2Nb_3Si_4$  with the  $Sc_2Re_3Si_4$  type and of  $\alpha Nb_5Si_3$ . The structures of both compounds are closely related and in as-cast alloys they were observed to crystallize in long needles or plates, which separate along a common crystallographic plane [2000Leb].

### Liquidus, Solidus and Solvus Surfaces

No information is available on liquidus, solidus or solvus surfaces. Alloys near the Si-U boundary with 10 at.% Si at 1000°C appeared partially molten [2000Leb]. Microstructures of as-cast alloys indicate primary precipitation of the ternary compounds  $U_2Nb_3Si_4$  and  $U_{2-x}Nb_{3+x}Si_4$ .

### Isothermal Sections

Phase equilibria have been established in an isothermal section at 1000°C [1993LeB, 2000Leb] and at 850°C [2000Leb]. The isothermal sections are presented in Figs. 1 and 2.

At 1000°C both ternary phases were observed without a homogeneity region and to form a narrow two-phase equilibrium. From the variation of lattice parameters in ternary multiphase alloys annealed at 1000°C small and in most cases negligible mutual solid solubilities among binary uranium and binary niobium silicides were concluded. This was particularly true for  $\alpha Nb_5Si_3$  and  $U_3Si_2$ , which from XMA

showed practically no solubility for uranium and niobium, respectively at 1000°C. Even in the as-cast alloys XMA revealed less than 0.6 at.% U in  $\alpha\text{Nb}_5\text{Si}_3$  and less than 1.5 at.% Nb in  $\text{U}_3\text{Si}_2$ . ( $\gamma\text{U,Nb}$ ) was never present in quenched alloys due to rapid decomposition below the monotectoid/eutectoid reaction temperature of the Nb–U binary revealing  $\alpha\text{U}$  instead. According to the Si–U binary, a small region of liquid phase appears near 90U10Si at 1000°C, which solidifies on quenching the samples giving rise to non-equilibrium structures.  $\alpha\text{Nb}_5\text{Si}_3$  was reported to be in equilibrium with the full range of the ( $\gamma\text{U,Nb}$ ) solid solution (see Fig. 1).

Phase equilibria at 850°C are characterized by the two ternary compounds:  $\text{U}_2\text{Nb}_3\text{Si}_4$  and closely related  $\text{U}_{2-x}\text{Nb}_{3+x}\text{Si}_4$ ,  $x \approx 0.25$ , both without homogeneity regions. There is practically no solid solubility of Nb in  $\text{U}_3\text{Si}_2$  (maximal solubility from EMPA: 59.5U0.1Nb40.4Si), in  $\text{U}_3\text{Si}$  (maximal solubility from EMPA: 75.3U0.1Nb24.6Si) and there is virtually no Si, Nb dissolved in the uranium matrix (maximal solubility from EMPA: 99.3U0.6Nb0.1Si) in contact with the ternary phase  $\text{U}_2\text{Nb}_3\text{Si}_4$ . The observed two-phase equilibria: ( $\gamma\text{U,Nb}$ ) +  $\text{U}_2\text{Nb}_3\text{Si}_4$  and  $\alpha\text{Nb}_5\text{Si}_3$  + ( $\gamma\text{U,Nb,Si}$ ) prove, that there is no compatibility between  $\text{U}_3\text{Si}_2$  fuel and niobium metal at 1000°C and at 850°C, respectively.

### Thermodynamics

No experimental thermodynamic data are presently available for the ternary system. As most of the binary boundary phases engage in two-phase equilibria with stoichiometric  $\text{U}_2\text{Nb}_3\text{Si}_4$ , a relatively high thermodynamic stability of this ternary compound could be inferred.

### Miscellaneous

The effect of 0.1 to 0.5 mass% Nb-additives on the corrosion resistance of  $\text{U}_3\text{Si}$  against water at 300°C under 90 MPa was investigated by [1993Kon]. The speed of corrosion was measured for various length of time from 100 to 1000 h. After 300 h the speed of corrosion, for instance, for the alloys with 0.4 mass% Nb was given as  $0.2 \text{ mg} \cdot (\text{cm}^{-2} \cdot \text{h})^{-1}$ . Niobium seems to decrease the rate of corrosion with amount (from 0.1 to 0.4 mass% Nb) and with time.

Magnetic properties of  $\text{U}_2\text{Nb}_3\text{Si}_4$  in the temperature range of 5–300 K and in fields up to 2 Tesla were described with an effective paramagnetic moment  $\mu_{\text{eff}} = 2.34 \mu_{\text{B}}/\text{U}_{\text{atom}}$ ,  $\Theta_{\text{p}} = -21 \text{ K}$  and a temperature independent term  $\chi_o = 33.9 \cdot 10^{-9} \text{ m}^3 \cdot \text{mol}^{-1}$ .  $\text{U}_2\text{Nb}_3\text{Si}_4$  was said to be weakly ferromagnetic below  $T_c \approx 35 \text{ K}$  with a rather small remanence of only  $0.0088 \mu_{\text{B}} \cdot \text{U}_{\text{atom}}^{-1}$ . A neutron powder diffraction experiment at 1.4 K failed to reveal any magnetic contribution, which suggested that the magnetic moments were certainly smaller than  $\sim 0.3 \mu_{\text{B}}$  [2000Leb].

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**Table 1:** Experimental Investigations of the Nb-Si-U Phase Relations, Structures and Properties

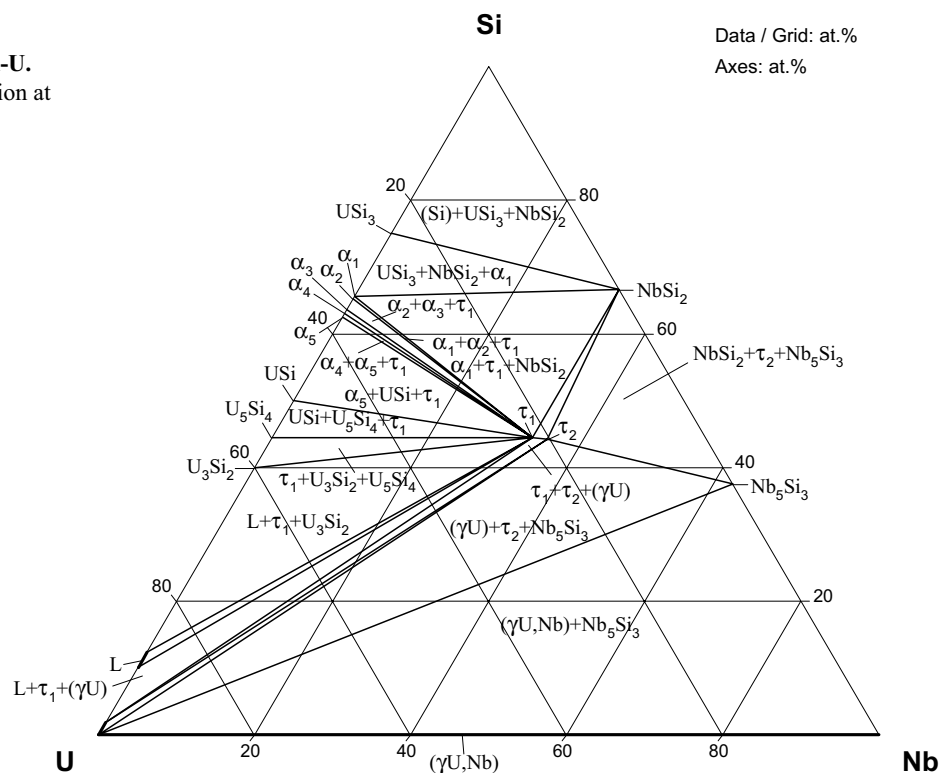
Reference	Method/Experimental Technique	Temperature/Composition/Phase Range Studied
[1993LeB]	Arc melting of elemental ingots under argon; heat treatment at 1000-1050°C. A single phase material of U <sub>2</sub> Nb <sub>3</sub> Si <sub>4</sub> was obtained from an alloy annealed at 1300-1400°C for 48 h in a W-sheet vacuum furnace. Measurement range for $\chi$ : $2 < T < 300$ K; magnetization at 5 K up to 2 Tesla.	Phase equilibria at 1000°C. Determination of the crystal structures of U <sub>2</sub> Nb <sub>3</sub> Si <sub>4</sub> from X-ray powder data. Neutron powder diffraction of U <sub>2</sub> Nb <sub>3</sub> Si <sub>4</sub> ( $\lambda = 0.24268$ nm, $T = 1.4$ K). Magnetic susceptibility $2 < T < 300$ K; magnetization $< 2$ Tesla at 5 K for U <sub>2</sub> Nb <sub>3</sub> Si <sub>4</sub> and UMo <sub>1.25</sub> Si <sub>0.75</sub> .
[1993Kon]	Arc-melted alloys U <sub>3</sub> Si annealed at 800°C for 100 h. Starting materials 99.8 mass% U, chemical analysis, XPD, metallography.	Investigation of the effect of 0.1 to 0.5 % Nb-additives on the corrosion resistance of U <sub>3</sub> Si in water at 300°C under 90 MPa (in an autoclave) from 100 to 1000 h.
[2000Leb]	Alloys prepared by arc melting or levitation melting in argon. Heat treatment at 1000°C on tungsten substrates in a high vacuum W-sheet furnace for 200 h. For equilibria at 850°C, samples within alumina crucibles were vacuum-sealed in quartz capsules and heat treated for 300 h and water quenched. Starting materials: 99.9 mass% U, 99.9% Nb, 99.9999% Si. Metallography, EMPA, X-ray powder diffraction. Neutron powder diffraction of U <sub>2</sub> Nb <sub>3</sub> Si <sub>4</sub> . Measurement range for $\chi$ : $2 < T < 300$ K; magnetization at 5 K up to 6 Tesla.	Phase equilibria at 1000°C and at 850°C. Determination of the crystal structure of U <sub>2</sub> Nb <sub>3</sub> Si <sub>4</sub> and of U <sub>2-x</sub> Nb <sub>3+x</sub> Si <sub>4</sub> , $x \approx 0.25$ from Rietveld refinements. Magnetic susceptibility $2 < T < 300$ K; magnetization $< 2.5$ Tesla at 5 K for U <sub>2</sub> Nb <sub>3</sub> Si <sub>4</sub> .

**Table 2:** Crystallographic Data of Solid Phases

Phase/ Temperature Range [°C]	Pearson Symbol/ Space Group/ Prototype	Lattice Parameters [pm]	Comments/References
(γU,Nb)	<i>cI2</i> <i>Im<math>\bar{3}m</math></i>		[Mas2]
(γU) 1135 - 774.8	W	$a = 353.35$	pure U; refined at 787°C, [Mas2]
(Nb) < 2469		$a = 330.04$	pure Nb [Mas2]
(Si) < 1414	<i>cF8</i> <i>Fd<math>\bar{3}m</math></i> C <sub>diamond</sub>	$a = 543.06$	[Mas2]
(βU) 774.8 - 667.7	<i>tP30</i> <i>P4<sub>2</sub>/mnm</i> βU	$a = 1075.89$ $c = 565.31$	[Mas2]
(αU) < 667.7	<i>oC4</i> <i>Cmcm</i> αU	$a = 285.37$ $b = 586.95$ $c = 495.48$	[Mas2]
Nb <sub>3</sub> Si 1975 - 1765	<i>tP32</i> <i>P4<sub>2</sub>/n</i> Ti <sub>3</sub> P	$a = 1022.4$ $c = 518.9$	[1995Sch]
βNb <sub>5</sub> Si <sub>3</sub> 2515 - 1645	<i>tI32</i> <i>I4/mcm</i> W <sub>5</sub> Si <sub>3</sub>	$a = 997$ $c = 508$	37.5 to 40.5 at.% Si, [1995Sch] Si rich [1995Sch]
		$a = 1004.0$ $c = 508.1$	Si poor [1995Sch]
αNb <sub>5</sub> Si <sub>3</sub> < 1935	<i>tI32</i> <i>I4/mcm</i> Cr <sub>5</sub> B <sub>3</sub>	$a = 657.1$ $c = 1188.9$	36.7 to 39.8 at.% Si [1995Sch]
NbSi <sub>2</sub> < 1935	<i>hP9</i> <i>P6<sub>2</sub>22</i> CrSi <sub>2</sub>	$a = 481.9$ $c = 659.2$	[1995Sch]
USi <sub>3</sub> < 1510	<i>cP4</i> <i>Pm<math>\bar{3}m</math></i> Cu <sub>3</sub> Au	$a = 403.53$	[1992Rem]
USi <sub>2</sub> < 450	<i>tI12</i> <i>I4<sub>1</sub>/amd</i> ThSi <sub>2</sub>	$a = 392.2$ $c = 1415.4$	(metastable), [1992Rem]
α <sub>1</sub> , USi <sub>2-x</sub> < 1710	<i>tI12</i> <i>I4<sub>1</sub>/amd</i> def-ThSi <sub>2</sub>	$a = 394.23$ $c = 1371.2$	USi <sub>1.88</sub> 65 at.% Si, [1992Rem]
α <sub>2</sub> , USi <sub>2-x</sub>	<i>oI12</i> <i>Imma</i> def-GdSi <sub>2</sub>	$a = 395.3$ $b = 392.9$ $c = 1365.6$	at 64 at.% Si, [1992Rem]

Phase/ Temperature Range [°C]	Pearson Symbol/ Space Group/ Prototype	Lattice Parameters [pm]	Comments/References
$\alpha_3$ , $\text{USi}_{2-y}$	<i>oP6</i> <i>Pmmm</i> (?) distorted $\text{AlB}_2$	$a = 389.3$ $b = 671.7$ $c = 404.2$	( $\text{U}_3\text{Si}_5\text{-o2}$ ) at ~ 63 at.% Si, [1992Rem]
$\alpha_4$ , $\text{USi}_{2-y}$	<i>oP6</i> <i>Pmmm</i> distorted $\text{AlB}_2$	$a = 386.4$ $b = 666.0$ $c = 407.3$	( $\text{U}_3\text{Si}_5\text{-o1}$ ) at 63 at.% Si, [1992Rem]
$\alpha_5$ , $\text{USi}_{2-y}$ < 1770	<i>hP3</i> <i>P6/mmm</i> defect $\text{AlB}_2$	$a = 384.75$ $c = 407.40$	( $\text{U}_3\text{Si}_5\text{-hex}$ or $\text{USi}_{1.67}$ ) [1992Rem]
USi < 1580	<i>tI138</i> <i>I4/mmm</i> USi	$a = 1058.7$ $c = 2431.0$	[1992Rem, 1993LeB, 1996LeB]
USi (metastable)	<i>oP8</i> <i>Pnma</i> FeB	$a = 758.5$ $b = 390.3$ $c = 566.3$	probably impurity (O) stabilized [1992Rem, 1993LeB]
$\text{U}_5\text{Si}_4$ < 1100	<i>hP18</i> <i>P6/mmm</i> $\text{U}_5\text{Si}_4$	$a = 1046.7$ $c = 391.2$	Single crystal study [2006Noe]
$\text{U}_3\text{Si}_2$ < 1665	<i>tP10</i> <i>P4/mbm</i> $\text{U}_3\text{Si}_2$	$a = 732.99$ $c = 390.04$	[V-C2, Mas2]
$\gamma\text{U}_3\text{Si}$ 930 - 759	<i>cP4</i> <i>Pm\bar{3}m</i> $\text{Cu}_3\text{Au}$	$a = 434.6$	[V-C2, 1965Str]
$\beta\text{U}_3\text{Si}$ 762 - -153	<i>tI16</i> <i>I4/mcm</i> $\beta\text{U}_3\text{Si}$	$a = 603.28$ $c = 869.07$	[V-C2, 1965Str]
$\alpha\text{U}_3\text{Si}$ < -153°C, at -193°C	<i>oF32</i> <i>Fmmm</i> $\alpha\text{U}_3\text{Si}$	$a = 865.4$ $b = 854.9$ $c = 852.3$	[V-C2, 1965Str]
* $\tau_1$ , $\text{U}_2\text{Nb}_3\text{Si}_4$	<i>tP36</i> $P4_12_12$ $\text{Sc}_2\text{Re}_3\text{Si}_4$ (ordered $\text{Zr}_5\text{Si}_4$ type)	$a = 703.89$ $c = 1298.4$	stoichiometric [2000Leb] $R_F = 0.046$
* $\tau_2$ , $\text{U}_{2-x}\text{Nb}_{3+x}\text{Si}_4$	<i>oP36</i> <i>Pnma</i> $\text{Ce}_2\text{Sc}_3\text{Si}_4$ (ordered $\text{Sm}_5\text{Ge}_4$ type)	$a = 0.6760$ $b = 1314.1$ $c = 693.2$	at 19.3U37.4Nb43.3Si (at.%) [2000Leb]

**Fig. 1: Nb-Si-U.**  
Isothermal section at  
1000°C



**Fig. 2: Nb-Si-U.**  
Isothermal section at  
850°C

